# **Panasonic**

Zener Diode DZ2J130×0L

## DZ2J130×0L Silicon epitaxial planar type

#### For constant voltage / For surge absorption circuit

- Features
- Excellent rising characteristics of zener current Iz •
- · Low zener operating resistance Rz
- · Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

Marking Symbol: SJ or SU

#### Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

_	■ Absolute Maximum Ratings Ta = 25 °C						
	Parameter	Symbol	Rating	Unit			
	Repetitive peak forward current	IFRM	200	mA			
	Total power dissipation <sup>*1</sup>	Symbol Rating	200	mW			
	Electrostatic discharge *2		kV				
	Junction temperature	Tj	150	°C			
	Operating ambient temperature	Topr	-40 to +85	°C			
	Storago tomporaturo	Teta	55 to ±150	ŝ			

Storage temperature Tstg -55 to +150 Note) \*1 Mounted on glass epoxy print board (  $45~mm \times 45~mm \times 1~mm$  ) Solder in (Recommended land pattern)

\*2 Test method : IEC61000\_4\_2

(C = 150 pF, R = 330  $\Omega$ , Contact discharge : 10 times )

#### ■ Electrical Characteristics Ta = 25 °C + 3 °C

Parameter	Symbol	Symbol Conditions		Тур	Max	Unit
Forward voltage	VF	IF = 10 mA			1.0	V
Zener voltage *1, *2	VZ	IZ = 5 mA	12.40		13.65	V
Zener operating resistance	RZ	IZ = 5 mA			35	Ω
Zener rise operating resistance	RZK	IZ = 0.5 mA			80	Ω
Reverse current	IR	VR = 10 V			0.05	μA
Temperature coefficient of zener voltage *3	SZ	IZ = 5 mA		10.9		mV/°C

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.

2. Absolute frequency of input and output is 5 MHz.

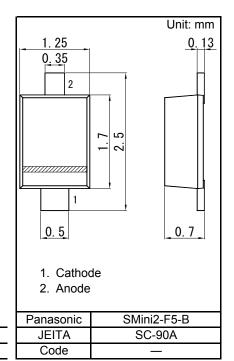
3. \*1 The temperature must be controlled 25 °C for VZ mesurement.

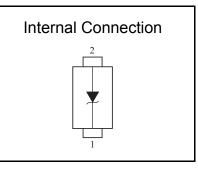
VZ value measured at other temperature must be adjusted to VZ (25 °C).

Rank classification \*2 VZ guaranted 20 ms after current flow

*3	Tj =	25	°C to	150	°C
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K classification							
Code	M			0			
Rank	М			No-rank			
VZ	12.74	to	13.40	12.40	to	13.65	
Marking symbol	SU		SJ				

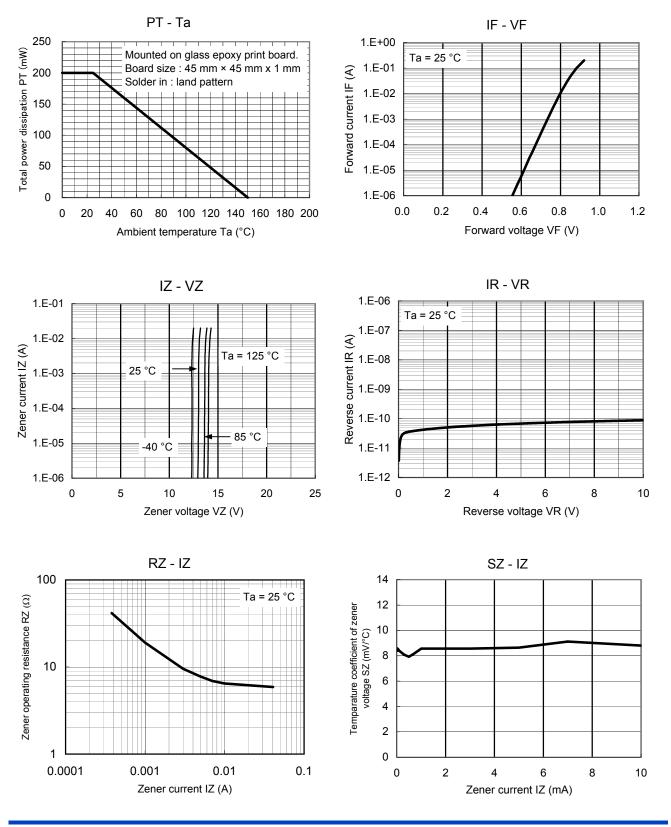






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### Technical Data (reference)



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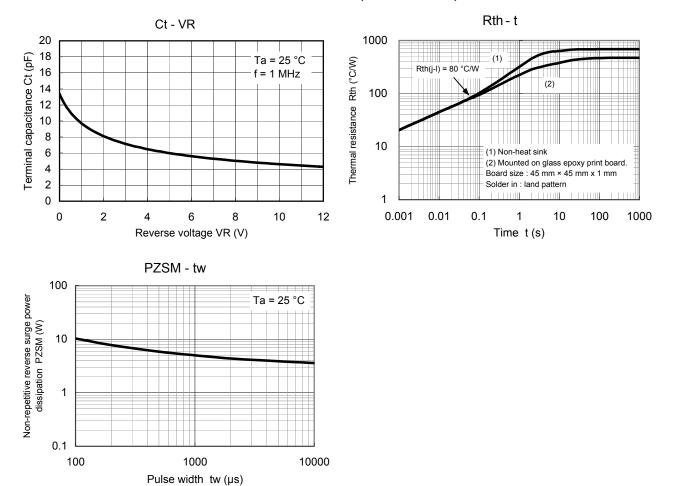
Established : 2009-10-14 Revised : 2013-07-12

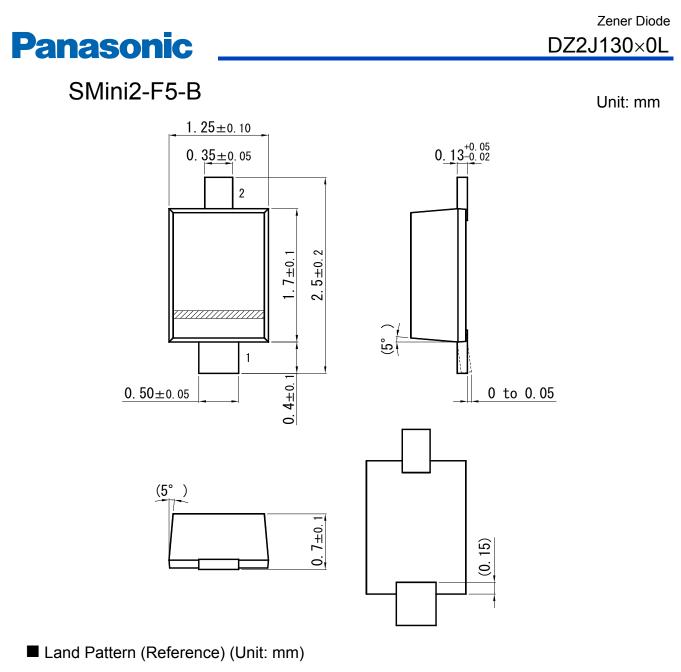


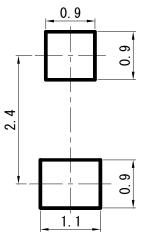


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